March 2006



FSUSB31 Low Power Dual SPST Hi-Speed USB 2.0 (480Mbps) Switch

Features

- Low On capacitance, 6.0pF (typical)
- Low On resistance, 6.5Ω (typical)
- Low power consumption (1µA maximum)
- 10µA maximum ICCT over and expanded control voltage range (V_{IN}=2.6V, V_{CC}=4.3V)
- Wide -3dB bandwidth, > 720MHz
- 8K I/O to GND ESD protection
- Power OFF protection when V_{CC} = 0V, D+/D- pins can tolerate up to 4.3V
- Packaged in:
 - Pb-Free 8-lead MicroPak[™] (1.6mm x 1.6mm)
 - Pb-Free 8-lead US-8 (preliminary)

Applications

- Cell phone, PDA, Digital Camera, and Notebook
- LCD Monitor, TV, and Set-top Box

General Description

The FSUSB30 is a Low Power, Dual SPST 2-Port Hi-Speed USB 2.0 switch. This part is configured as a single pole, single throw switch and is optimized for switching or isolating a Hi-Speed (480Mbps) source or a Hi-Speed and Full Speed (12Mbps) source. The FSUSB31 is compatible with the requirements of USB2.0 and features an extremely low On Capacitance (C_{ON}) of 6.0pF. The wide bandwidth of this device (>720MHz), exceeds the bandwidth needed to pass the 3rd harmonic, resulting in signals with minimum edge and phase distortion. Superior channel-to-channel crosstalk also minimizes interference.

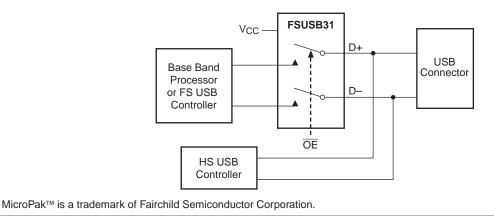
The FSUSB31 contains special circuitry on the D+/Dpins which allows the device to withstand an overvoltage condition. This device is also designed to minimize current consumption even when the control voltage applied to the \overline{OE} pin, is lower than the supply voltage (V_{CC}). This feature is especially valuable to Ultra-Portable applications such as cell phones, allowing for direct interface with the General Purpose I/Os of the baseband processor. Other applications include port isolation and switching in portable cell phones, PDAs, digital cameras, printers, and notebook computers.

Ordering Information

Order Number	Package Number	Package Description
FSUSB31K8X (Preliminary)	MAB08A	Pb-Free 8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide
FSUSB31L8X	MAC08A	Pb-Free 8-Lead MicroPak, 1.6 mm Wide

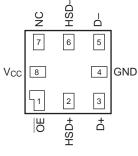
Pb-Free package per JEDEC J-STD-020B.

Application Diagram

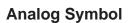


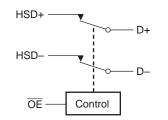
Connection Diagrams

Pad Assignments for MicroPak



(Top View)

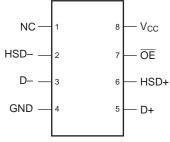




Pin Descriptions

Pin Name	Description
ŌĒ	Bus Switch Enable
D+, D–, HSD+, HSD–	Data Ports
NC	No Connect

Pin Assignment for US8



(Top Through View)

Truth Table

ŌĒ	Function				
Н	Disconnect				
L	D+, D– = HSD				

Absolute Maximum Ratings

The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.)

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +4.6V
V _S	DC Input Voltage ⁽¹⁾	-0.5V to +4.6V
V _{IN}	DC Switch Voltage ⁽¹⁾	
	HSD	–0.5V to V _{CC} + 0.3V
	D+, D-	-0.5V to +4.6V
	DC Input Diode Current	–50mA
	DC Output Current	50mA
	Storage Temperature	–65°C to +150°C
	ESD (Human Body Model)	
	All Pins	7.5kV
	I/O to GND	8kV

Recommended Operating Conditions⁽²⁾

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	3.0V to 4.3V
V _{IN}	Control Input Voltage	0V to V _{CC}
	Switch Input Voltage	0V to V _{CC}
	Operating Temperature	–40°C to +85°C

Notes:

1. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed. DC switch voltage may never exceed 4.6V.

2. Control input must be held HIGH or LOW and it must not float.

DC Electrical Characteristics

(All typical values are @ 25°C unless otherwise specified.)

				T _A = -	+85°C		
Symbol	Parameter	Conditions	$V_{CC}(V)$	Min	Тур	Max	Units
V _{IK}	Clamp Diode Voltage	I _{IN} = -18mA	3.0			-1.2	V
V _{IH}	Input Voltage HIGH		3.0 to 3.6	1.3			V
			4.3	1.7			
V _{IL}	Input Voltage LOW		3.0 to 3.6			0.5	V
			4.3			0.7	
I _{IN}	Control Input Leakage	$V_{IN} = 0V \text{ to } V_{CC}$	4.3	-1.0		1.0	μΑ
I _{OZ}	OFF State Leakage	$0 \le HSD \le V_{CC}$	4.3	-2.0		2.0	μΑ
I _{OFF}	Power OFF Leakage Current (D+, D–)	$V_{IN} = 0.0V$ to 4.3V, $V_{CC} = 0V$	0	-2.0		2.0	μΑ
R _{ON}	Switch On Resistance ³	$V_{IN} = 0.4V, I_{ON} = -8mA$	3.0		6.5	10.0	Ω
ΔR_{ON}	Delta R _{ON} ⁴	$V_{IN} = 0.4V, I_{ON} = -8mA$	3.0		0.35		Ω
R _{ON} Flatness	R _{ON} Flatness ³	$V_{IN} = 0.0V - 1.0V,$ $I_{ON} = -8mA$	3.0		2.0		Ω
I _{CC}	Quiescent Supply Current	$V_{IN} = 0.0V \text{ or } V_{CC}, \ I_{OUT} = 0$	4.3			1.0	μΑ
ICCT	Increase in I_{CC} Current per Control Voltage and V_{CC} Levels	V _{IN} = 2.6V, V _{CC} = 4.3V	4.3			10.0	μΑ

AC Electrical Characteristics

(All typical values are for V_{CC} = 3.3V @ 25°C unless otherwise specified.)

				T _A = -	40°C to	+85°C		Figure
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Тур	Max	Units	Number
t _{ON}	Turn On Time, OE to Output	$V_{IN} = 0.8V, R_L = 50\Omega,$ $C_L = 5pF$	3.0 to 3.6		15.0	30.0	ns	Figure 8
t _{OFF}	Turn OFF Time. OE to Output	$V_{\text{IN}} = 0.8 \text{V}, \text{ R}_{\text{L}} = 50 \Omega,$ $C_{\text{L}} = 5 \text{pF}$	3.0 to 3.6		12.0	25.0	ns	Figure 8
t _{PD}	Propagation Delay ⁴	$R_L = 50\Omega, C_L = 5pF$	3.3		0.25		ns	Figure 6 Figure 7
Т _{ВВМ}	Break-Before-Make	$ \begin{array}{l} R_{L} = 50\Omega, \ C_{L} = 5pF, \\ V_{IN} = 0.8V \end{array} $	3.0 to 3.6	2.0		6.5	ns	Figure 9
O _{IRR}	OFF Isolation (Non-Adjacent)	$R_{T} = 50\Omega$, f = 240MHz	3.0 to 3.6		-35.0		dB	Figure 12
Xtalk	Non-Adjacent Channel Crosstalk	$R_T = 50\Omega$, f = 240MHz	3.0 to 3.6		-55.0		dB	Figure 13
BW	-3dB Bandwidth	$R_T = 50\Omega, C_L = 0pF$	3.0 to 3.6		720		MHz	Figure 11
		$R_T = 50\Omega, C_L = 5pF$	1		550			

Notes:

3. Measured by the voltage drop between Dn, HSD, Dn pins at the indicated current through the switch. On Resistance is determined by the lower of the voltage on the two ports.

4. Guaranteed by characterization.

USB Hi-Speed Related AC Electrical Characteristics

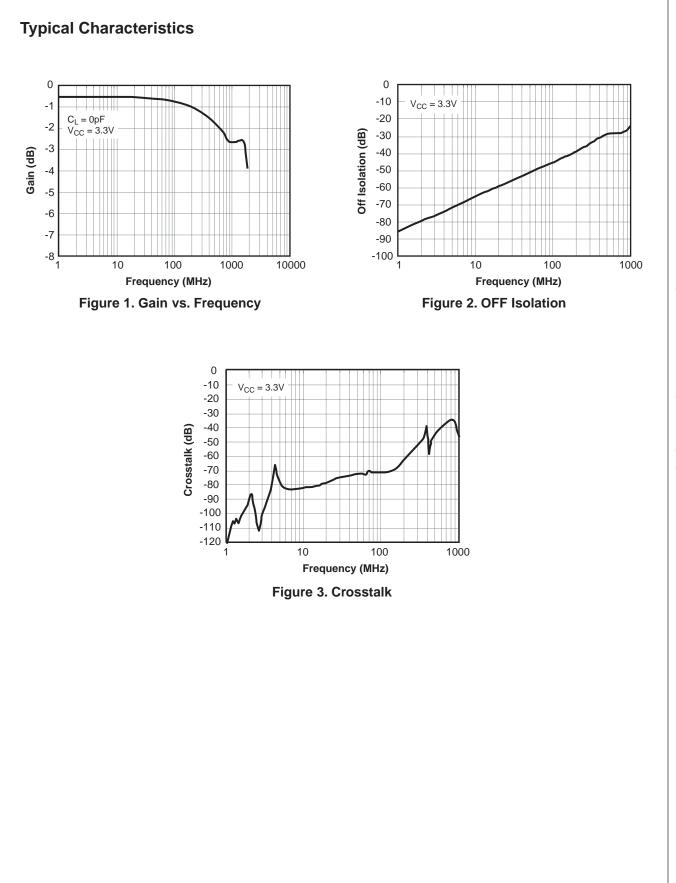
Symbol	Parameter	Conditions	V _{CC} (V)	$T_A = -4$	40°C to	Units	Figure	
	i alameter	Conditions	• 66 (•)	Min	Тур	Мах	Units	Number
t _{SK(O)}	Channel-to-Channel Skew ⁵	C _L = 5pF	3.0 to 3.6		50.0		ps	Figure 6 Figure 10
t _{SK(P)}	Skew of Opposite Transitions of the Same Output ⁵	C _L = 5pF	3.0 to 3.6		20.0		ps	Figure 6 Figure 10
t _J	Total Jitter ⁵	$R_L = 50\Omega, C_L = 5pF,$ $t_R = t_F = 500ps at 480 Mbps$ (PRBS = 2 ¹⁵ - 1)	3.0 to 3.6		200		ps	

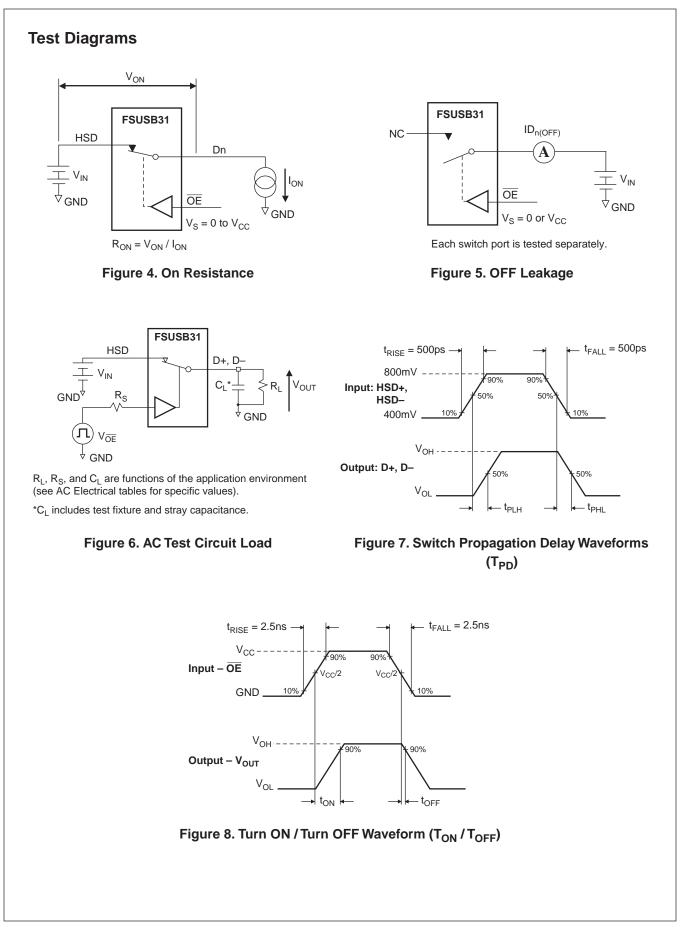
Notes:

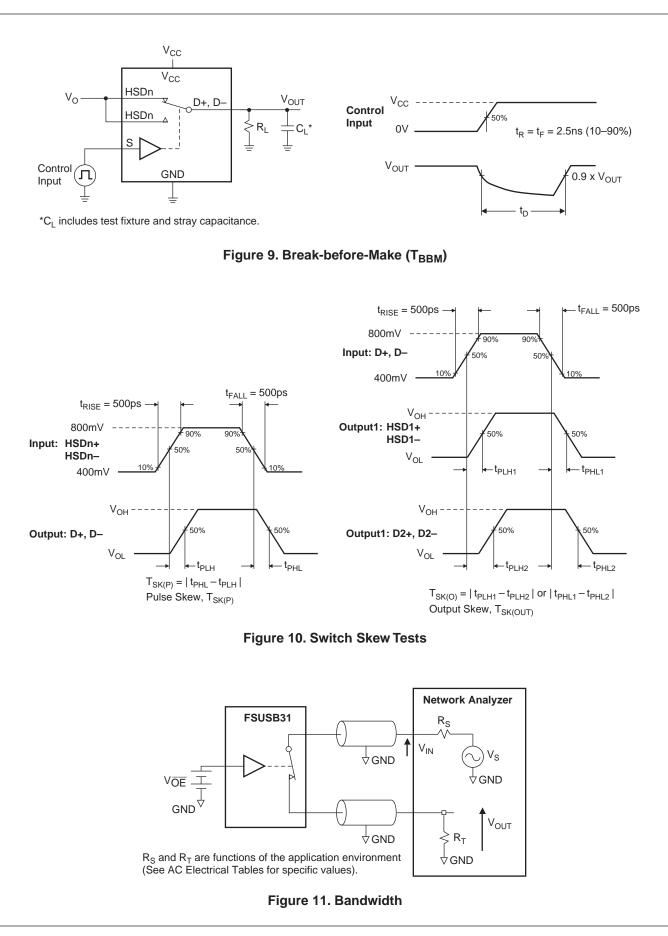
5. Guaranteed by design.

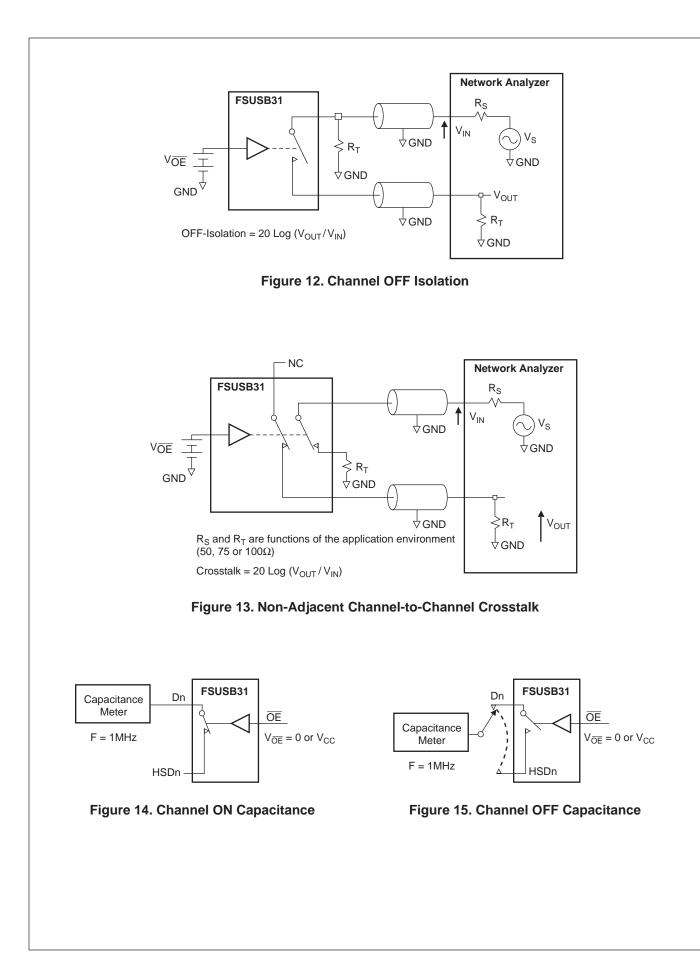
Capacitance

Symbol	Parameter	Conditions	T _A = -	40°C to	Units	Figure	
Symbol	i arameter	Conditions	Min	Тур	Max	Units	Number
C _{IN}	Control Pin Input Capacitance	$V_{CC} = 0V$		1.0		pF	Figure 15
C _{ON}	D1 _n , D2 _n , Dn ON Capacitance	$V_{CC} = 3.3, \overline{OE} = 0V$		6.0		pF	Figure 14
C _{OFF}	D1 _n , D2 _n OFF Capacitance	V_{CC} and $\overline{OE} = 3.3$		1.7		pF	Figure 15









Tape and Reel Specification

Tape Format for MircoPak

Package Designator	Tape Section	Number Cavities	Cavity Status	Cover Tape Status
L8X	Leader (Start End)	125 (typ)	Empty	Sealed
	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

Tape Dimension inches (millimeters)

300038

300033

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SCALE: 6X

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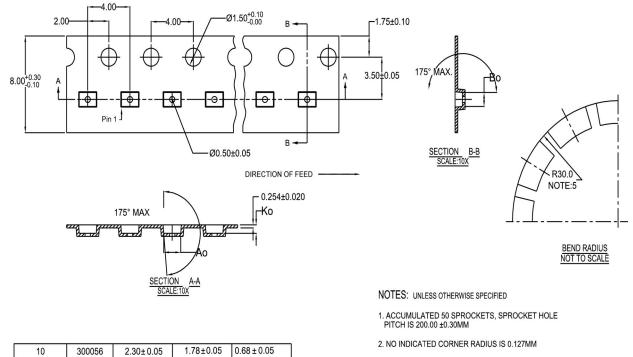
8 6

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 1.78 ± 0.05

 1.60 ± 0.05

0



1.78±0.05

 1.15 ± 0.05

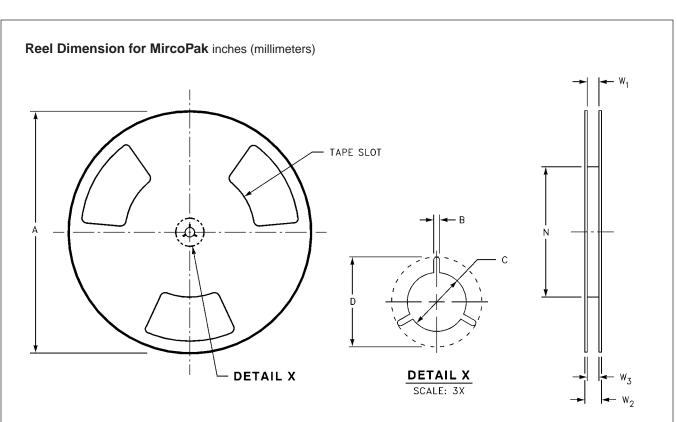
 0.68 ± 0.05

 0.70 ± 0.05

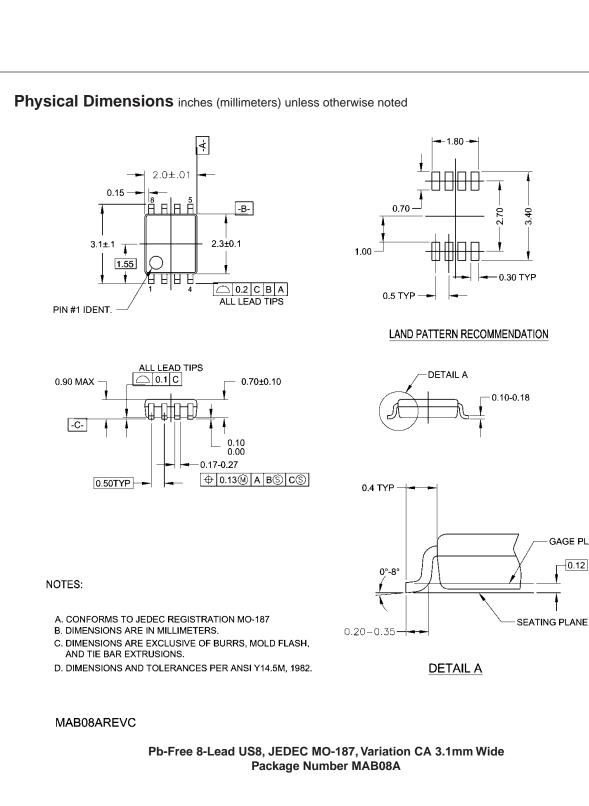
3. CAMBER	NOT TO EXCEED	1MM IN 100MM

4. SMALLEST ALLOWABLE BENDING RADIUS

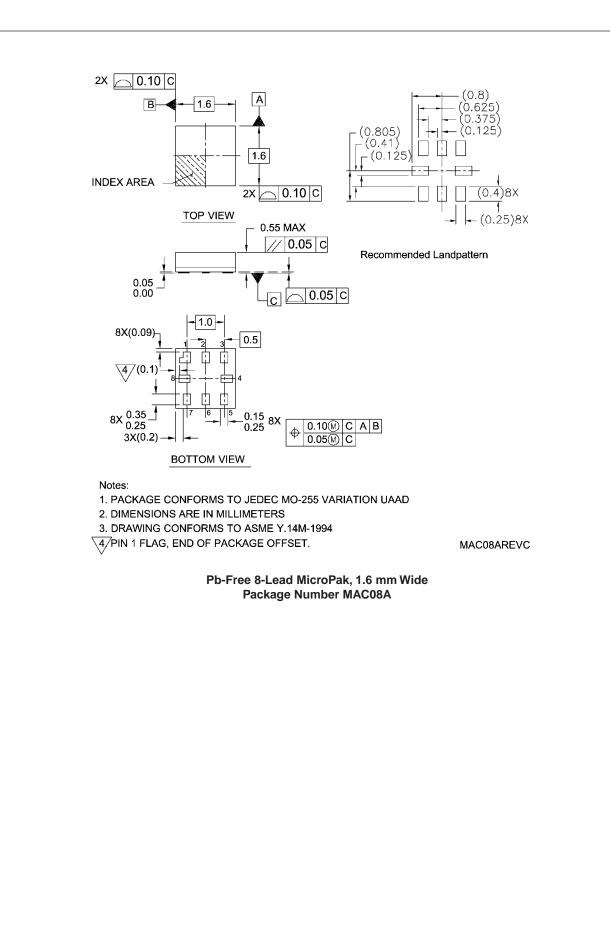
5. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT POCKET HOLE



Tape Size	Α	В	С	D	Ν	W1	W2	W3
8 mm	7.0	0.059	0.512	0.795	2.165	0.331 + 0.059/-0.000	0.567	W1 + 0.078/-0.039
	(177.8)	(1.50)	(13.00)	(20.20)	(55.00)	(8.40 + 1.50/-0.00)	(14.40)	(W1 + 2.00/-1.00)



GAGE PLANE 0.12



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E ² CMOS™	i-Lo™	OCX™	µSerDes™	UltraFET [®]
EnSigna™	ImpliedDisconnect [™]	OCXPro™	ScalarPump™	UniFET™
FACT™	IntelliMAX™	OPTOLOGIC®	SILENT SWITCHER [®]	VCX™
FACT Quiet Series™		OPTOPLANAR™	SMART START™	Wire™
Across the board. Around the world. [™] The Power Franchise [®] Programmable Active Droop [™]		PACMAN™	SPM™	
		POP™	Stealth™	
		Power247™	SuperFET™	
		PowerEdge™	SuperSOT™-3	

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